

**DEPARTMENT OF SCIENCES, IV SEMESTER M.Sc (Physics)  
END SEMESTER EXAMINATIONS, APRIL/MAY 2019**

**SUBJECT CONDENSED MATTER PHYSICS-II [PHY 5010]  
(REVISED CREDIT SYSTEM-2017)**

Time: 3 Hours

Date: 30<sup>TH</sup> April 2019

MAX. MARKS: 50

Note: (i) Answer **ALL** questions

(ii) Draw diagrams, and write equations wherever necessary

1. (a) Explain how a superconductor can be used to make a magnet and a cryotron.  
(b) What are the assumptions in London's theory? Derive the expression for penetration depth and comment on its temperature dependence.  
(c) What is Meissner effect? Show that a superconductor is a perfectly diamagnetic material. **[3+5+2]**
  
2. (a) Explain the terms – intermediate state, surface energy and coherence.  
(b) State the assumptions of Ginzburg-Landau theory. Derive the two G.L. equations.  
(c) Derive the expression for fluxoid. **[2+5+3]**
  
3. (a) What is electron lattice interaction? Using this explain the formation of Cooper pairs.  
(b) Using BCS theory, show that a bound state exists irrespective of smallness of attractive potential.  
(c) Describe Josephson tunneling using pendulum analogy. **[3+5+2]**
  
4. (a) Describe Landau's theory of phase transition. Discuss superfluidity of He-3.  
(b) Using the concept of diffusion, derive the expression for total width of depletion layer.  
(c) What is Schottky effect? For a metal-and n-type semiconductor junction, draw the energy level diagrams when no contacts are made and also when the junction is forward biased. **[3+4+3]**

**P.T.O.**

5. (a) Explain the terms- radiative and non-radiative transitions. Elucidate the working of a diode laser.
- (b) With appropriate diagrams, describe the construction and working of a p-n junction solar cell.
- (c) An abrupt  $p^+n$  junction in Ge is doped with donors and acceptors concentrations of  $N_a = 10^{22}/m^3$  and  $N_d = 10^{22}/m^3$  respectively. Determine the diffusion potential and space-charge layer width. Given  $\epsilon_r = 16$ ,  $n_i = 2.2 \times 10^{19}/m^3$ ,  $\epsilon_0 = 8.85 \times 10^{-12} F/m$ .
- [3+3+4]**